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COMPLEMENTARY SILICON PLASTIC POWER TRANSISTORS

... designed for use in general purpose power amplifier and switching applications.

FEATURES:

* Collector-Emitter Sustaining Voltage -V_{CEO(sus)}= 40V(Min)- TIP31,TIP32 60V(Min)- TIP31A,TIP32A 80V(Min)- TIP31B,TIP32B 100V(Min)-TIP31C,TIP32C

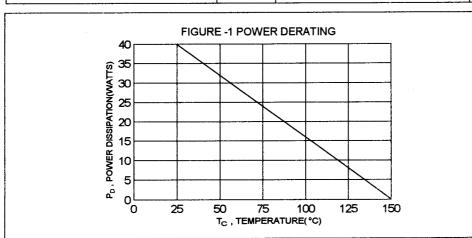
* Collector-Emitter Saturation Voltage- $V_{CE(sat)}$ =1.2V(Max)@ I_{C} = 3.0 A * Current Gain-Bandwidth Product f_{T} =3.0 MHz (Min)@ I_{C} =500 mA

MAXIMUM RATINGS

Characteristic	Symbol	TIP31 TIP32	TIP31A TIP32A	TIP31B TIP32B	TIP31C TIP32C	Unit
Collector-Emitter Voltage	V _{CEO}	40	60	80	100	V
Collector-Base Voltage	V _{CBO}	40	60	80	100	٧
Emitter-Base Voltage	V _{EBO}	5.0			٧	
Collector Current - Continuous - Peak	lc	3.0 5.0			A	
Base Current	i _B	1.0				Α
Total Power Dissipation@T _C = 25°C Derate above 25°C	P _D			10 32		W/°C
Operating and Storage Junction Temperature Range	T _J ,T _{STG}		-65 to	+150		°C

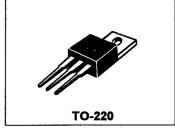
THERMAL CHARACTERISTICS

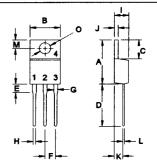
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rθjc	3.125	°C/W



NPN	PNP
TIP31	TIP32
TIP31A	TIP32A
TIP31B	TIP32B
TIP31C	TIP32C

3 AMPERE **COMPLEMENTARY SILICON POWER TRANSISTORS** 40 -100 VOLTS 40 WATTS





PIN 1.BASE 2.COLLECTOR 3.EMITTER 4.COLLECTOR(CASE)

DIM	MILLIMETERS			
	MIN	MAX		
Α	14.68	15.31		
В	9.78	10.42		
С	5.01	6.52		
D	13.06	14.62		
E	3.57	4.07		
F	2.42	3.66		
G	1.12	1.36		
H	0.72	0.96		
1	4.22	4.98		
J	1.14	1.38		
K	2.20	2.97		
L	0.33	0.55		
М	2.48	2.98		
0	3.70	3.90		

ELECTRICAL CHARACTERISTICS (T_c = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage(1) (I _C = 30 mA, I _B = 0)	TIP31,TIP32 TIP31A,TIP32A TIP31B,TIP32B TIP31C,TIP32C	V _{CEO(sus)}	40 60 80 100		٧
	1P32,TIP31A,TIP32A 1P32B,TIP31C,TIP32C	I _{CEO}		0.3 0.3	mA
Collector Cutoff Current (V _{CE} = 40 V, V _{EB} = 0) (V _{CE} = 60 V, V _{EB} = 0) (V _{CE} = 80 V, V _{EB} = 0) (V _{CE} = 100 V, V _{EB} = 0)	TIP31,TIP32 TIP31A,TIP32A TIP31B,TIP32B TIP31C,TIP32C	Ices		0.2 0.2 0.2 0.2	mΑ
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)		I _{EBO}		1.0	mA
ON CHARACTERISTICS (1)					
DC Current Gain (I _C = 1.0 A, V _{CE} = 4.0 V) (I _C = 3.0 A, V _{CE} = 4.0 V)		hFE	25 10	50	
Collector-Emitter Saturation Voltage (I _C = 3.0 A, I _B =375 mA)		V _{CE(sat)}		1.2	٧
Base-Emitter On Voltage (I _C =3.0 A, V _{CE} = 4.0 V)		V _{BE(on)}		1.8	V
DYNAMIC CHARACTERISTICS		*			
Current Gain - Bandwidth Product (2) (I _C = 500 mA , V _{CE} = 10 V , f _{TEST} = 1 M	Hz)	f _T	3.0		MHz
Small Signal Current Gain (I _C = 500 mA , V _{CE} = 10 V , f = 1 kHz)		h _{fe}	20		

⁽¹⁾ Pulse Test: Pulse width \leq 300 μ s , Duty Cycle \leq 2.0 %

⁽²⁾ $f_T = |h_{f_0}| \cdot f_{TEST}$

FIGURE 2 - SWITCHING TIME EQUIVALENT CIRCUIT

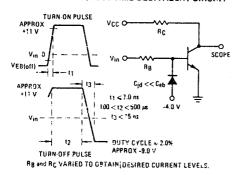


FIG-4 DC CURRENT GAIN

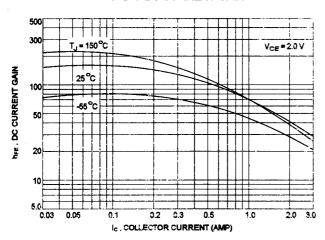


FIG-6 ACTIVE REGION SAFE OPERATING AREA

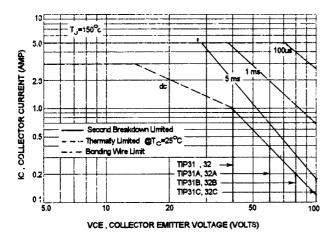


FIG-3 TURN-ON TIME

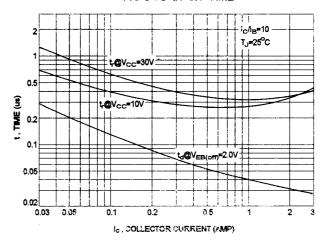
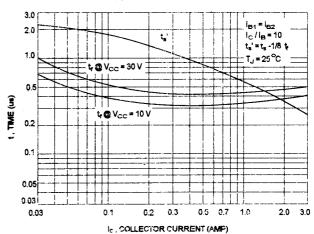


FIG-5 TURN-OFF TIME



There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of FIG-6 curve is base on $T_{J(PK)}$ =150 °C; T_C is variable depending on power level, second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)} \le 150$ °C, At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



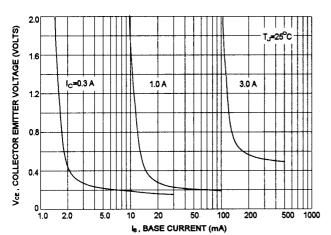


FIG-8 CAPACITANCES

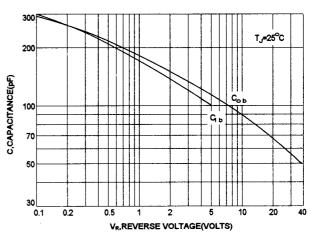


FIG-9 "ON" VOLTAGE

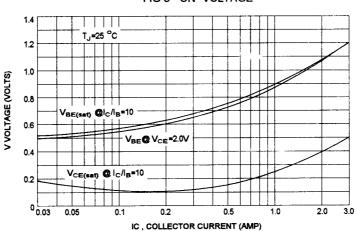


FIG-10 COLLECTOR CUT-OFF REGION

